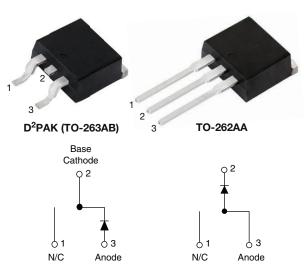
AY. www.vishay.com

# VS-15ETX06S-M3, VS-15ETX06-1-M3

#### Vishay Semiconductors

Hyperfast Rectifier, 15 A FRED Pt<sup>®</sup>



VS-15ETX06S-M3

VS-15ETX06-1-M3

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	15 A				
V <sub>R</sub>	600 V				
V <sub>F</sub> at I <sub>F</sub>	1.5 V				
t <sub>rr</sub> (typ.)	18 ns				
T <sub>J</sub> max.	175 °C				
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA				
Circuit configuration	Single				

#### **FEATURES**

- · Benchmark ultralow forward voltage drop
- · Hyperfast recovery time
- Low leakage current
- 175 °C operating junction temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V			
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 133 °C	15				
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	170	А			
Peak repetitive forward current	I <sub>FM</sub>		30				
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	PARAMETER SYMBOL TEST CONDITIONS				MAX.	UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-			
Forward valtage	V	I <sub>F</sub> = 15 A	-	2.3	3.2	V		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	1.5	1.8			
		$V_{R} = V_{R}$ rated	-	0.1	50			
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	40	300	μA		
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	20	-	pF		
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH		

RoHS

COMPLIANT HALOGEN



# VS-15ETX06S-M3, VS-15ETX06-1-M3

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### **Vishay Semiconductors**

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_C = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CC	NDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A},  dI_F/dt = 100$	A/ $\mu$ s, V <sub>R</sub> = 30 V	-	18	22		
Poverae receiven time	+	$I_F = 15 \text{ A}, \text{ d}I_F/\text{d}t = 10$	0 A/µs, V <sub>R</sub> = 30 V	-	20	32		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	22	-	ns	
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 15 A dI <sub>F</sub> /dt = 200 A/μs V <sub>B</sub> = 390 V	-	52	-		
Pook receivery ourrent		T <sub>J</sub> = 25 °C		-	2.4	-	Α	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	5.1	-	A	
	0	T <sub>J</sub> = 25 °C	-	-	25	-		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C	-	-	150	-	nC	
Reverse recovery time	t <sub>rr</sub>		I <sub>F</sub> = 15 A	-	37	-	ns	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	dl <sub>F</sub> /dt = 800 A/µs	-	16	-	А	
Reverse recovery charge	Q <sub>rr</sub>		V <sub>R</sub> = 390 V	-	350	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C		
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	1.0	1.3			
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>	R <sub>thJA</sub> Typical socket mount		-	70	°C/W		
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-			
Waight			-	2.0	-	g		
Weight			-	0.07	-	oz.		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Marking davias		Case style D <sup>2</sup> PAK (TO-263AB)		15ET	X06S			
Marking device		Case style TO-262AA	15ETX06-1					



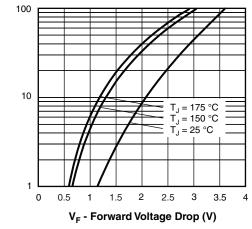
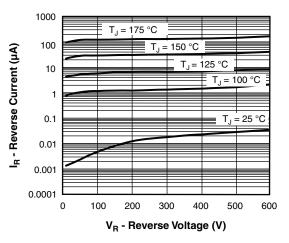
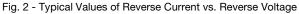


Fig. 1 - Typical Forward Voltage Drop Characteristics





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## VS-15ETX06S-M3, VS-15ETX06-1-M3

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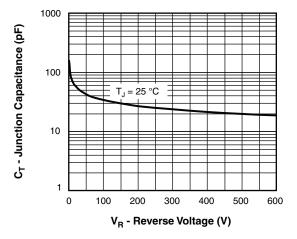


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

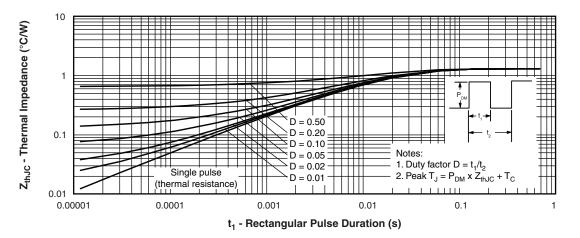


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

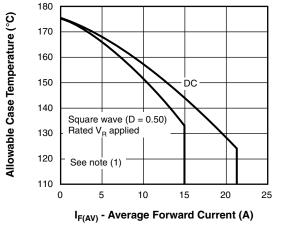


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

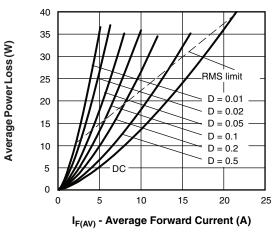


Fig. 6 - Forward Power Loss Characteristics

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## VS-15ETX06S-M3, VS-15ETX06-1-M3

V<sub>R</sub> = 390 V

T<sub>J</sub> = 125 °C T<sub>J</sub> = 25 °C

 $I_{F} = 30 \text{ A}$ 

= 15 A

dl<sub>F</sub>/dt (A/µs)

Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

450

400

350

300

250

200

150

100 50

0

100

Q<sub>rr</sub> (nC)



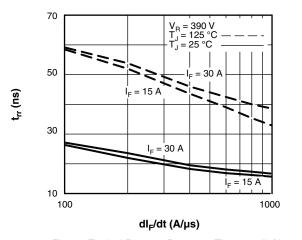


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 6); Pd<sub>REV</sub> = inverse power loss =  $V_{B1} \times I_R$  (1 - D);  $I_R$  at  $V_{B1}$  = rated  $V_R$ 

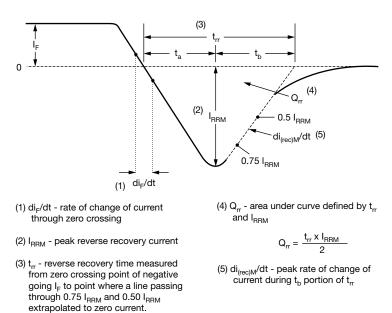


Fig. 9 - Reverse Recovery Waveform and Definitions

**Vishay Semiconductors** 

1000



## Vishay Semiconductors

#### **ORDERING INFORMATION TABLE**

www.vishay.com

Device code	VS-	15	Е	т	x	06	s	TRL	-M3
	1	2	3	4	5	6	$\overline{7}$	8	9
			0						
	Ë.			niconduc		Dauct			
	2			ng (15 A	A)				
	3 -		single o						
	4 -	. Т=	TO-220	), D <sup>2</sup> PAł	<				
	5 -	- X =	hyperfa	ist recov	very				
	6 -	- Vol	tage rati	ng (06 =	= 600 V)				
	7.	• s	= D <sup>2</sup> PA	K					
		• -1	= TO-2	62					
	8 -	• N	one = tu	be (50 p	pieces)				
				e and re		orienter	$for D^2$	PAK na	ickade)
					•				• /
				be and r		it orient	eu, ior l	J-PAN	ласкаде
	9			ntal digit:					
		-M3	= halog	en-free	, RoHS-	complia	ant, and	termina	tions le

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-15ETX06S-M3	50	1000	Antistatic plastic tubes					
VS-15ETX06STRR-M3	800	800	13" diameter plastic tape and reel					
VS-15ETX06STRL-M3	800	800	13" diameter plastic tape and reel					
VS-15ETX06-1-M3	50	1000	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS					
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164			
Dimensions	TO-262	www.vishay.com/doc?96165			
Part marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444			
Fart marking mormation	TO-262	www.vishay.com/doc?95443			
Packaging information		www.vishay.com/doc?96424			

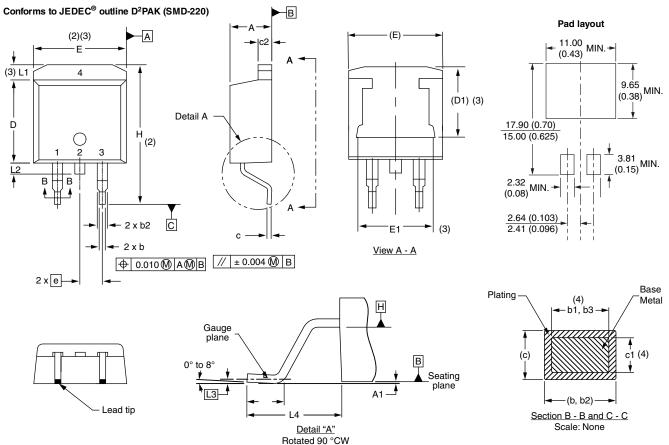
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D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches

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<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	MILLIMETERS		INCHES	
STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

.....

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

Controlling dimension: inches (6)

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

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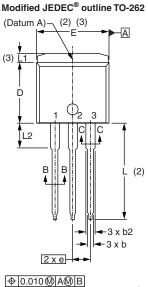
## **Outline Dimensions**

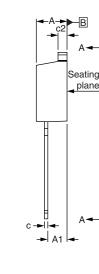


**Vishay Semiconductors** 

**TO-262AA** 

#### **DIMENSIONS** in millimeters and inches





D1 (3) (3) F1 Section A - A (4) Base Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None

F

0.010 🕅	AM B	



Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode

Lead assignments

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

 <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the state back. the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

Revision: 30-Nov-17

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